

Analyzing System on A Chip Single Event Upset Responses using Single Event Upset Data, Classical Reliability Models, and Space Environment Data

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2. NASA/GSFC

To be presented by Melanie Berg at the RADECS 2017 Radiation Effects on Components and Systems (RADECS) Conference, Geneva, Switzerland, October 6, 2017.

Acronyms



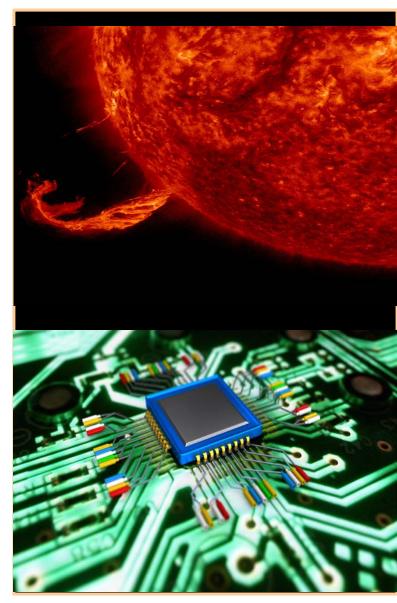
- Combinatorial logic (CL)
- Commercial off the shelf (COTS)
- Complementary metal-oxide semiconductor (CMOS)
- Device under test (DUT)
- Edge-triggered flip-flops (DFFs)
- Electronic design automation (EDA)
- Error rate (λ)
- Error rate per bit(λ_{bit})
- Error rate per system(λ_{system})
- Field programmable gate array (FPGA)
- Global triple modular redundancy (GTMR)
- Hardware description language (HDL)
- Input output (I/O)
- Intellectual Property (IP)
- Linear energy transfer (LET)
- Mean fluence to failure (MFTF)
- Mean time to failure (MTTF)
- Number of used bits (#Usedbits)
- Operational frequency (fs)
- Personal Computer (PC)

- Probability of configuration upsets (P_{configuration})
- Probability of Functional Logic upsets (P_{functionalLogic})
- Probability of single event functional interrupt (P_{SEFI})
- Probability of system failure (P_{system})
- Processor (PC)
- Radiation Effects and Analysis Group (REAG)
- Reliability over time (R(t))
- Reliability over fluence (R(Φ))
- Single event effect (SEE)
- Single event functional interrupt (SEFI)
- Single event latch-up (SEL)
- Single event transient (SET)
- Single event upset (SEU)
- Single event upset cross-section (σ_{SEU})
- System on a chip (SoC)
- Windowed Shift Register (WSR)
- Xilinx Virtex 5 field programmable gate array (V5)
- Xilinx Virtex 5 field programmable gate array radiation hardened (V5QV)



Problem Statement

- Conventional methods of applying single event upset (SEU) data to complex systems need improvement.
- The problem boils down to extrapolation and application of SEU data to characterize system performance in radiation environments.





Abstract – Impact to Community

- We are investigating the application of classical reliability performance metrics combined with standard SEU analysis data.
- We expect to relate SEU behavior to system performance requirements...
 - Our proposed methodology will provide better prediction of SEU responses in harsh radiation environments with confidence metrics.



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SEU System Analysis Is Not Simple Algebra

- When a system is targeted for space, single event effect (SEE) data are obtained for all devices that make up that system.
- Combining component data is not simple addition.
- Co-dependent susceptibilities exist and must be handled accordingly.



Proposed method should target critical missions subjected to ionizing particles.



Scope of Presentation

- Full system analysis requires combining SEU data for a variety of devices across a variety of boxes/mediums.
- The scope of this presentation is for System-type SEU data analysis for a single device.
- In this presentation, a System on a Chip (SoC) field programmable gate array (FPGA) device is used as an example.
- Future work will expand to address full systems.

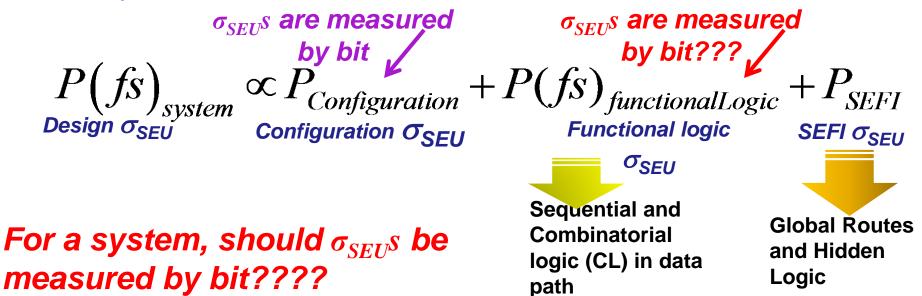
This presentation is a simplified approach for SEU data extrapolation to complex systems. Future work will incorporate details for a more realistic analysis.

Background (1) FPGA SEU Susceptibility



SEU Cross Section (σ_{SEU})

- σ_{SEU} s (per category) are calculated from SEU test and analysis.
- σ_{SEU}s are calculated with particles that vary in linear energy transfer (LET).
- FPGA architectures vary and so do their SEU responses.
- Most believe the dominant $\sigma_{SEU}s$ are per bit (configuration or flipflops (DFFs)). However, global routes are significant (more than DFFs).



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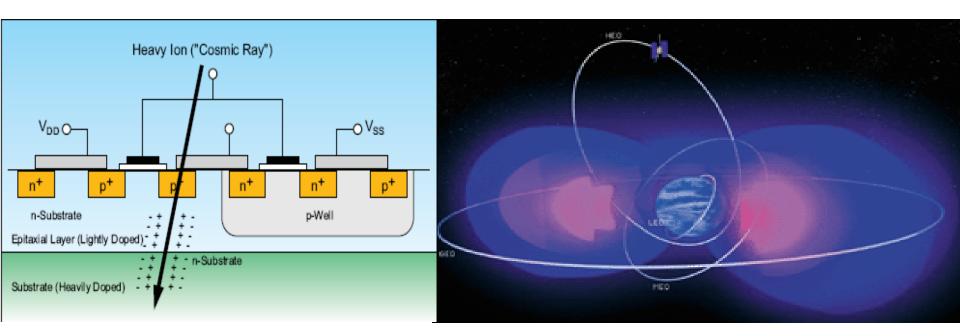


Background (2) Conventional Conversion of SEU Cross-Sections To Error Rates for Complex Systems First Step

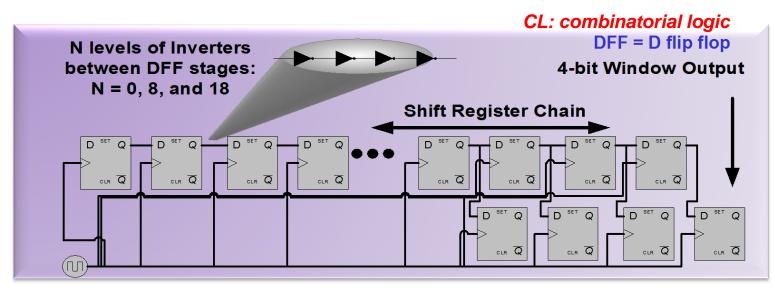
 $\sigma_{SEU} = #errors/fluence$ $\lambda_{system} = #errors/time$

LET: Linear energy transfer

 Perform SEU accelerated radiation testing across ions with different linear energy transfers (LETs) to calculate σ_{SEU}s per LET.



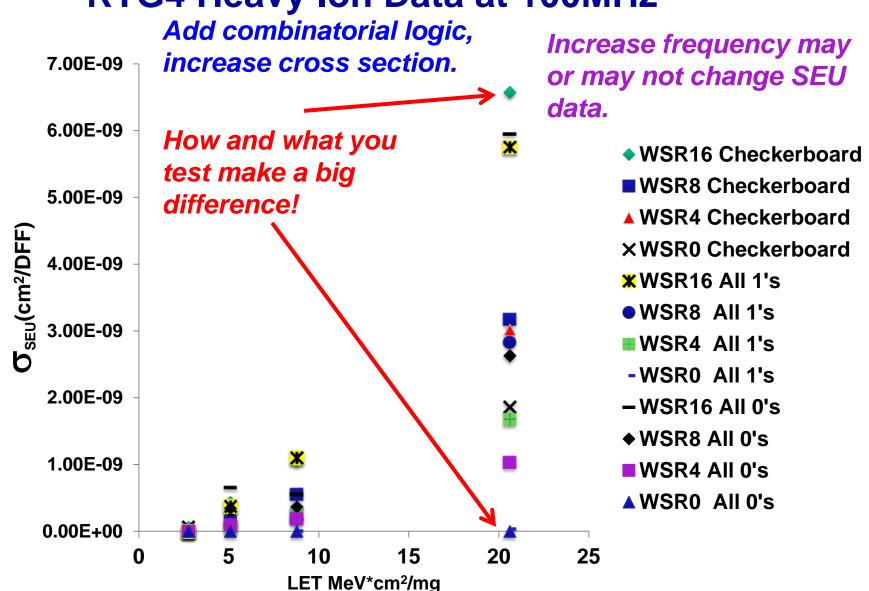
Windowed Shift Register (WSR) Test Structures Are Used To Obtain SEU Data



- Shift registers are typical test structures (mapped into device under test (DUT)) used for accelerated radiation testing.
- Purpose is to analyze DFF and CL susceptibility.

Windowed Shift Register (WSR) Microsemi – RTG4 Heavy Ion Data at 100MHz

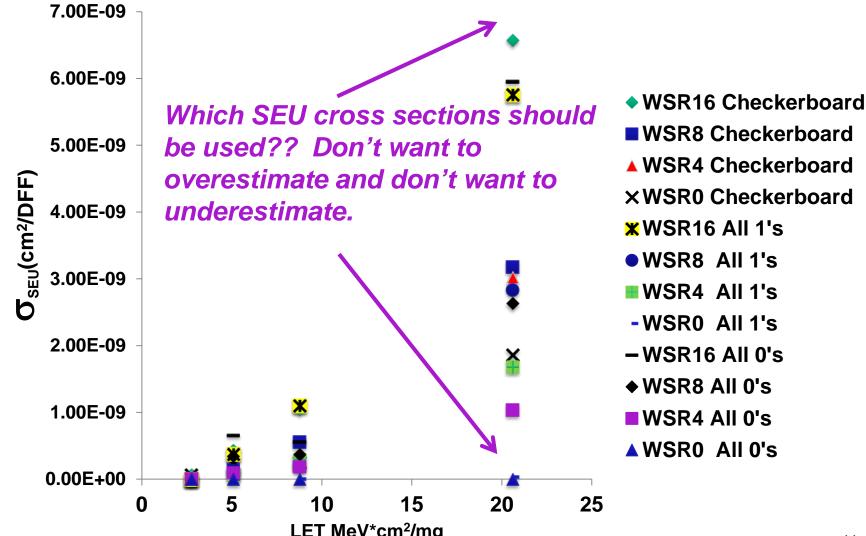




What If Tests Do Not Investigate Test Structures Across A Variety of Parameters



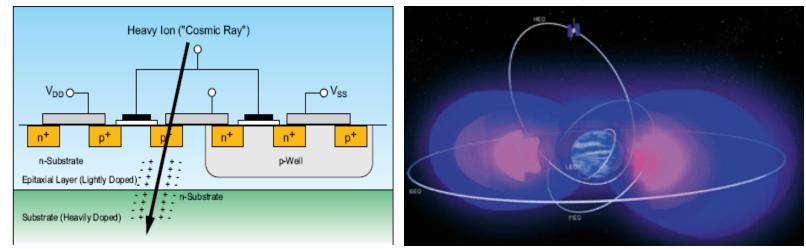
Data might not reflect potential SEU responses!



Background (3) Conventional Conversion of SEU Cross-Sections To Error Rates for Complex Systems Next Step

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- **Bottom-Up approach (transistor level)**:
 - Given σ_{SEU} (per bit) use an error rate calculator (such as CRÈME96) to obtain an error rate per bit (λ_{bit}).
 - Multiply λ_{bit} by the number of used memory bits (#UsedBits) in the target design to attain a system error rate (λ_{system}). Configuration and DFFs.
- Top-Down approach (system level):
 - Given σ_{seu} (per system) use an error rate calculator (such as CRÈME96) to obtain an error rate per bit (λ_{system}).



Understand Goal of SEU Testing and Data Application

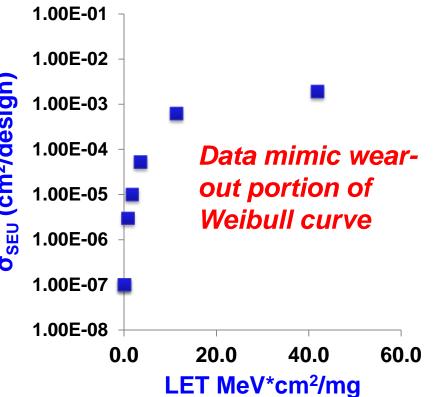
- Is the goal of SEU testing to analyze test circuits?
 - Efficacy of DFF mitigation.
 - Single event transient (SET) propagation strength.
 - SET width.
 - General test circuit evaluation.
- Or... is the goal of testing to obtain data for eventual system characterization?
- System characterization requires more than conventional test circuit analysis.
 - Test circuits are too simple.
 - Test circuits often do not follow formal design rules (e.g., synchronous, CMOS balancing, or place and route).
 - Design topology affects SEU response.
- Complex system test structures are important for SEU system characterization.
 - Top down approach.
 - Multiple complex test structures and trend evaluation is essential.



Technical Problems with Current Methods of Error Rate Calculation

b

- For submission to CREME96, σ_{SEU} data (in Log-linear form) are fitted to a Weibull curve.
 - The two main parameters for curve fitting are a shape factor and a slope factor. (cm²/design
 - During the curve fitting process, a large amount of error can be introduced.
 - Consequently, it is possible for resultant error rates (for the same design) to vary by decades.
- Because of the error rate calculation process, σ_{SEU} data are blended together and it is nearly impossible to hone in on the problem spots. This can become important for mitigation insertion.



Technical Problems with Bottom-Up Analysis Method (1)

- Multiplying each bit within a design by λ_{bit} is not an efficient method of system error rate prediction.
 - Works well with memory structures...
 but...complex systems do not operate or respond like memories.
 - If an SEU affects a bit, and the bit is either inactive, disabled, or masked, a system malfunction might not occur.
 - Using the same multiplication factor across DFFs will produce extreme overestimates.





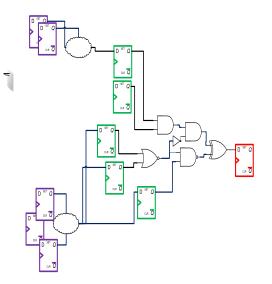
- To this date, there is no accurate method to predict system state activity for complex systems.
- Fault injection or simulation will not determine frequency of activity. Any electronic design automation (EDA) tool supplier will agree.

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Technical Problems with Bottom-Up Analysis Method (2)

- There are a variety of components that are susceptible to SEUs (clocks, resets, combinatorial logic, flip-flops (DFFs, etc...)).
 - Various component susceptibilities are not accurately characterized at a per bit level.
 - Design topology makes a significant difference in susceptibility and is not characterized in error rate calculators (e.g., CREME96).
 - As a result, there's a lot of hand-waving during data extrapolation.

Error rates calculated at the transistor-bit level are estimated at too small of granularity for proper extrapolation to complex systems.





Let's Not Reinvent The Wheel... A Proven Solution Can Be Found in Classical Reliability Analysis

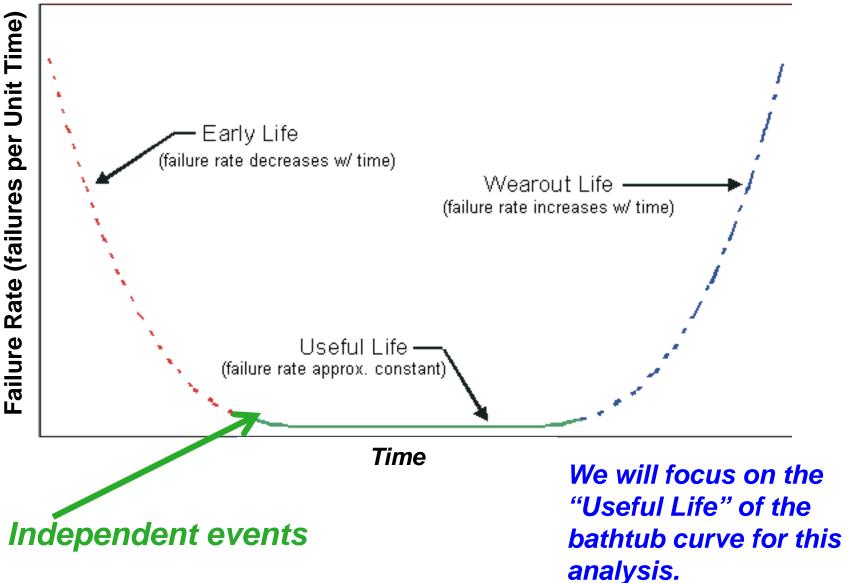
- Classical reliability models have been used as a standard metric for complex system performance.
- The analysis provides a more in depth interpretation of system behavior over time by using system-level MTTF data for system performance metrics.

 $R(t)=e^{-t/MTTF}$ or $R(t)=e^{-\lambda t}$

Theory is already developed, proven, and should be in our hands!

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Weibull Failure Rate (λ(T)) Bathtub Curve



assumes that during useful-lifetime: Failures are independent. $R(t)=e^{-t/MTTF}$ or $R(t)=e^{-\lambda t}$

The exponential model that relates reliability to MTTF

- Error rate is constant.
- MTTF = $1/\lambda_{a}$
- For a given LET (across fluence):
 - SEUs are independent.
 - σ_{SEU} is constant.
 - MFTF = $1/\sigma_{SEU}$.
- Hence, mapping from the time domain to the fluence domain (per LET) is straight forward:

 $K(t) = e^{-t/MTTF}$

- t⇔Φ
- MTTF 🖨 MFTF

 $-\lambda \Leftrightarrow \sigma_{SEU}$

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Mapping Classical Reliability Models from The Time Domain To The Fluence Domain

Weibull slope = 1... exponential.

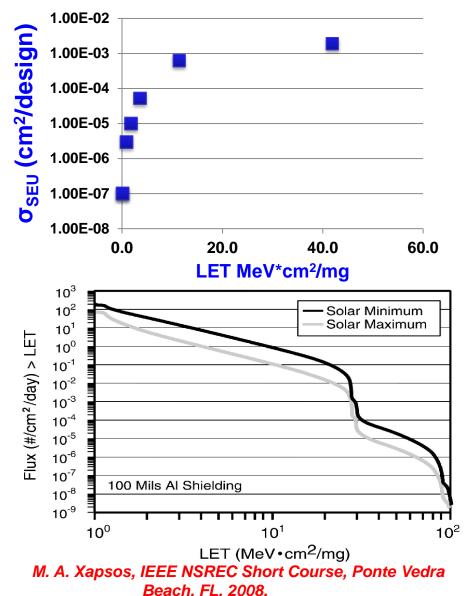
Parallel between time and fluence.

 $\sigma_{SEU} = \# errors / fluence$ $\lambda_{system} = #errors/time$

$$(\Phi) = e^{-\Phi/MFTF}$$

Creating Reliability Curves from σ_{SEU} s

- σ_{SEU} data are system level.
- A histogram of environment data is created. Bins are determined by LET values at each σ_{SEU} data point.
- For each data point at a given LET, a combination of binned environment data and upperbound σ_{SEU} data are used to determine system reliability performance.
- A piecemeal approach is performed per data point to determine the weakest points of system performance.







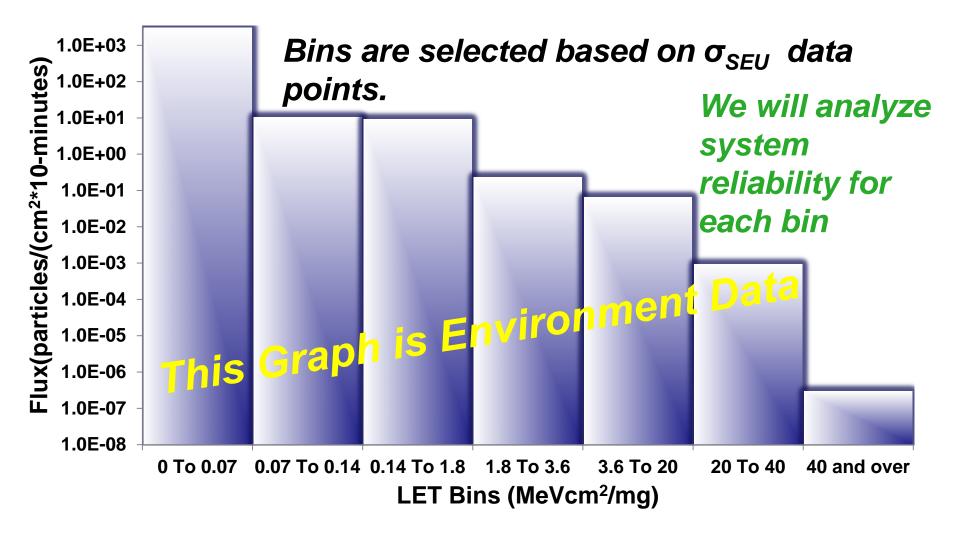
Example of Proposed Methodology Application

- Mission requirements:
 - The FPGA shall contain an embedded microprocessor.
 - Selection shall be made between a Xilinx V5QV (very expensive device) or a Xilinx V5 with embedded PowerPC (relatively cheap device).
 - FPGA operation shall have reliability of 3-nines (99.9%) within a 10 minute window at Geosynchronous Equatorial Orbit (GEO).
- Proposed methodology:
 - Create a histogram of particle flux versus LET for a 10minute window of time for your target environment.
 - Calculate MFTF per LET (obtain SEU data).
 - Graph R(Φ) for a variety of LET values and their associated MFTFs. R(Φ)=e^{- Φ /MFTF}
 - For selected ranges of LETs, use an upper bound of particle flux (number of particles/cm²•10-minutes), to determine if the system will meet the mission's reliability requirements.

Environment Data: Flux versus LET Histogram for A 10-minute Window



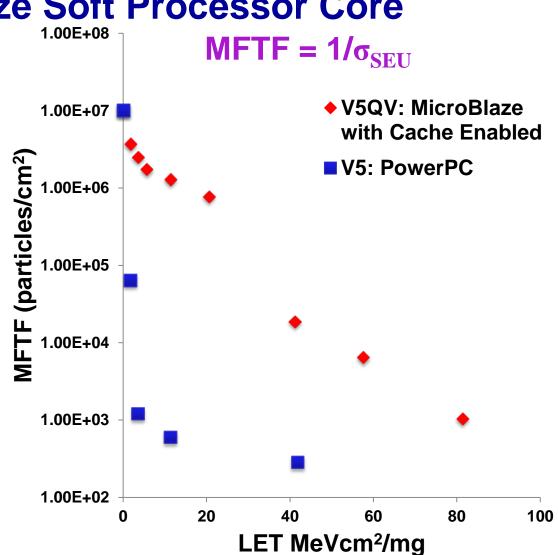
Geosynchronous Equatorial Orbit (GEO) 100-mils shielding



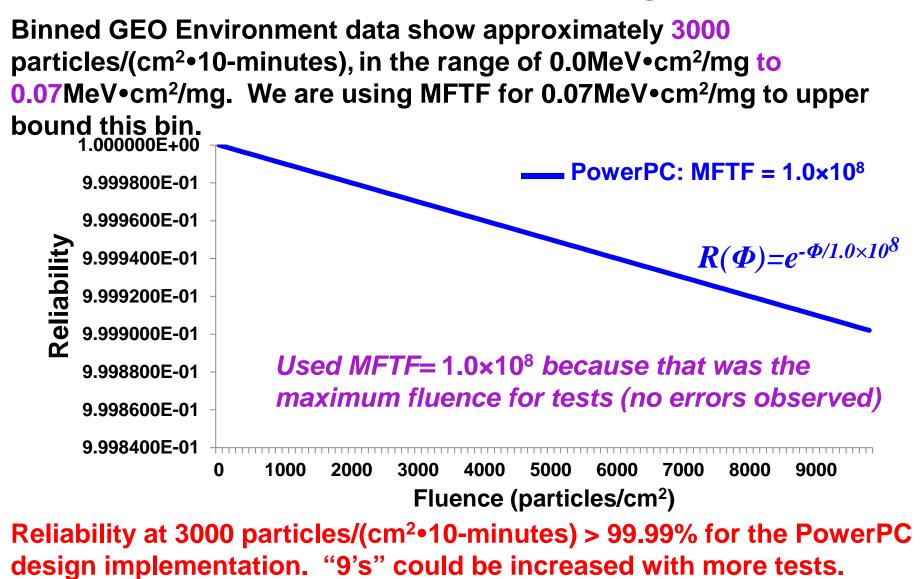
MFTF versus LET for the Xilinx V5 Embedded PowerPC Core and the Xilinx V5QV MicroBlaze Soft Processor Core

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- V5QV: no system errors were observed below LET=1.8MeV•cm²/mg. Total fluence > 5.0×10⁸ particles/cm².
- PowerPC:
 - No system errors were observed below
 LET=0.07MeV•cm²/mg with total fluence = 1.0×10⁸ particles/cm².
 - Hence, at 0.07, we will assume an upper-bound MFTF = 1.0×10⁸ particles/cm².
 - More tests would increase the MFTF for this bin.

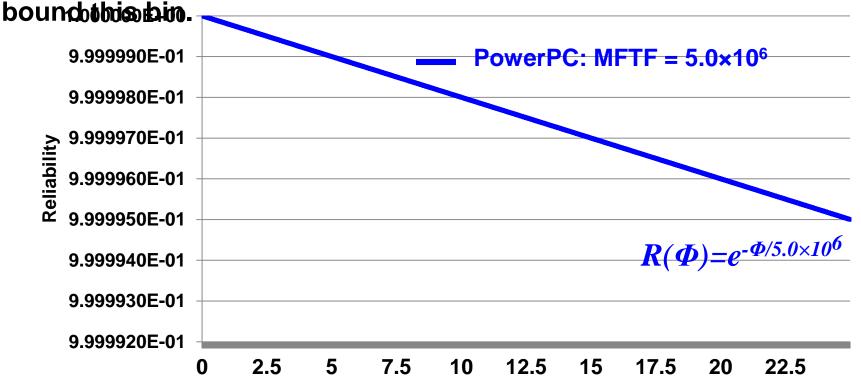


Reliability across Fluence up to LET=0.07MeV•cm²/mg



Reliability across Fluence up to LET=0.14MeV•cm²/mg

Binned GEO Environment data show approximately 11 particles/(cm²•10-minutes), in the range of 0.07MeV•cm²/mg to 0.14MeV•cm²/mg. We are using MFTF for 0.1MeV•cm²/mg to upper

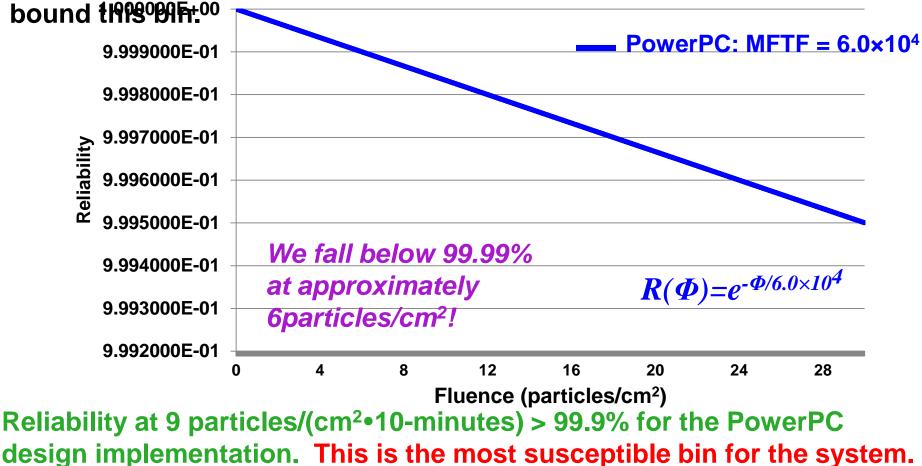


Fluence (particles/cm²) Reliability at 5 particles/(cm²•10-minutes) > 99.999% for the V5QV PowerPC design implementation.

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Reliability across Fluence up to LET=1.8 MeV•cm²/mg





Reliability across Fluence up to LET=3.6MeV•cm²/mg

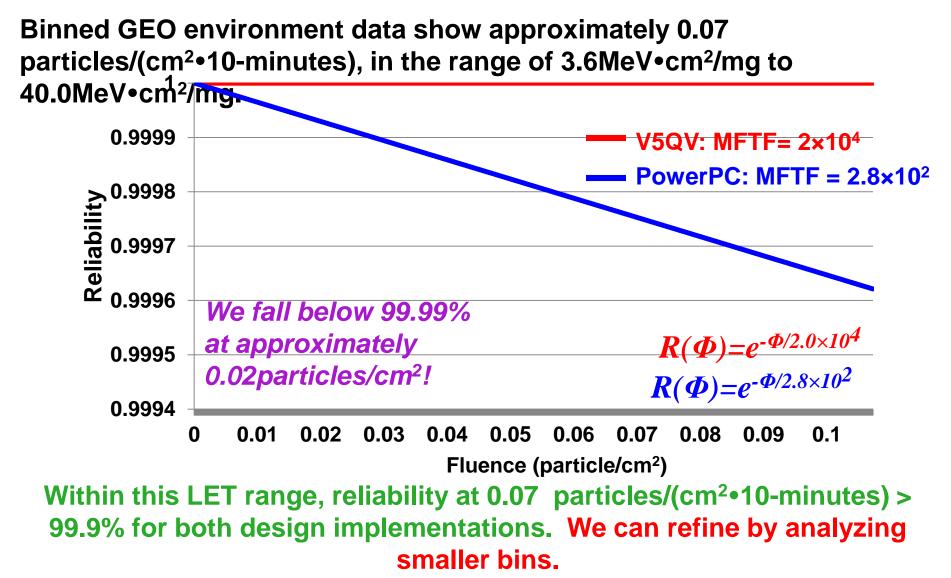


Binned GEO Environment data show approximately 0.23 particles/(cm²•10-minutes), in the range of 1.8MeV•cm²/mg to 3.6MeV•cm²/mg. 1.00000E+00V5QV: MFTF= 2.5×10⁶ 9.99950E-01 PowerPC: MFTF = 1.2×10^3 9.99900E-01 Reliability 9.99850E-01 9.99800E-01 $\frac{R(\Phi) = e^{-\Phi/2.5 \times 10^6}}{R(\Phi) = e^{-\Phi/1.2 \times 10^3}}$ 9.99750E-01 9.99700E-01 2 3 10 5 6 8 9 0 1 4 7 Fluence (particle/cm²)

Within this LET range, reliability at 0.23 particles/(cm²•10-minutes) > 99.999% for both design implementations.



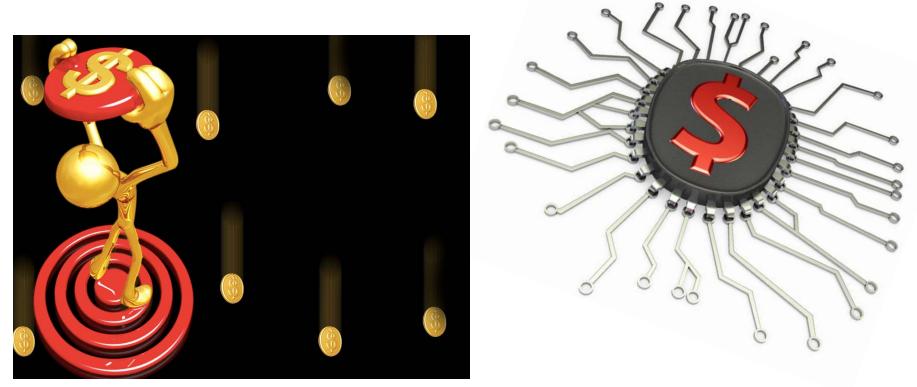
Reliability across Fluence at LET=40MeVcm²/mg





Example Conclusion

- Using the proposed methodology, the commercial Xilinx V5 device will meet project requirements.
- In this case, the project is able to save money by selecting the significantly cheaper FPGA device and gain performance because of the embedded PowerPC.





Conclusions

- This study transforms proven classical reliability models into the SEU particle fluence domain. The intent is to better characterize SEU responses for complex systems.
- The method for reliability-model application is as follows:
 - SEU data are obtained as MFTF.
 - Reliability curves (in the fluence domain) are calculated using MFTF; and are analyzed with a piecemeal approach.
 - Environment data are then used to determine particle flux exposure within required windows of mission operation.
- The proposed method does not rely on data-fitting and hence removes a significant source of error.
- The proposed method provides information for highly SEUsusceptible scenarios; hence enables a better choice of mitigation strategy.
- This is preliminary work. There is more to come.

This methodology expresses SEU behavior and response in terms that missions understand via classical reliability metrics.

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Acknowledgements

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